⑩ 日本国特許庁(JP)

n 特許出額公開

0公開特許公報(A)

昭61-97102

@Int_Cl.4

做別記号

庁内整理番号

◎公開 昭和61年(1986)5月15日

C 01 B 3/06 B 01 J 19/12 7918-4G 6812-4G

客査請求 未請求 発明の数 1 (全4頁)

公発明の名称 光酸化還元法

②特 购 昭59-217569

②出 顧昭59(1984)10月17日

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発明の名称

光酸化亚元法

ュ 特許請求の範囲

- (1) 半導体微粒子と溶液とを接触させた反応系化光 を照射させて酸化源元反応を起こさせる光酸化谱 元法において、光ファイバーの側面に半導体微粒 子を担持せしめて半導体微粒子つき光ファイバー とし、数半導体微粒子つき光ファイバーを溶と 接触させた後疎光ファイバーを通して光ファイバー 側面の反応系に光を照射することを特徴とする 光酸化温元法。
- (2) 放光ファイバーがステップ形又はグレーデッド 形光ファイバーであり、放光ファイバーの別口角 又は関口角よりもわずかに大きな入射角で放光ファイバーに光を入射させる特許請求の範囲第1項 記載の光線化進元法。
- ュー発明の辞職な説明

(産業上の利用分野)

本発明は、半導体微粒子を用いた光酸化湿元法 に関し、特に効率の良い光酸化湿元法に関する。 (従来技術)

近年、微粒子光触性に関する研究が急速に発展している。これは光エキルギーを酸化チョン
(TiO2)、硫化カドミウム (CdS)などの半導体微粒子に吸収させ、生じた電子、正孔を用いて水分子(またはプロトン)を還元させたり、水又は有機物を酸化させる方法である。(例えばTrigger/983年//月号,47~53頁)

従来、上記光度化選元法の反応進行のための光の照射方法としては③ビーカー・フラスコ等の容器に半導体機粒子および溶液を入れ半導体機粒子 が底に沈静した状態で光を照射する方法、②上記反応液を提择させ半導体微粒子を溶液中に浮遊させた状態で光を照射する方法、③多孔質ガラス体に半導体微粒子を担持させ溶液に沈めて光を照射する方法。(例えば窯葉協会昭和38年度年会予構集375~374(出32))等が知られている。

(発明が解決しようとする問題点)

本発明は従来の光酸化運元法よりも効率の良い光酸化退元法を提供することをその目的とし、特に吸光特性を持つ溶液又は数乱を多くおこす溶液について反応進行が難しかった従来法の問題点の解決をはかるものである。

(問題点を解決するための手段)

上記問題点を解決するために、本発明は光ファイパーの側面に半導体微粒子を担持せしめて半導体微粒子のき光ファイパーとし、該半導体微粒子のき光ファイパーを溶液と接触させた後、該光フ

ないものが好まれる。

又本発明によれば、反応に関与できる反応系の 表面植も、反応容器内に充填される半導体微粒子 つき光ファイバーの本数を増加することによって 容易に広げられる。

以下に本発明を実施例に基ささらに詳細に説明する。

(災 施 例)

まず特級基務の TiC 84を加水分解させて TiO₂ 登立で 2.27 4モル/ 6 の TiO₂ ヒドロソル溶液 ァイパーを選して半導体機粒子と溶液とからなる 反応系に光を脱射することを特徴とする光線化温 元法を提供する。

本発明に使用する光ファイバーはガラス製 , ア ラスチァク製等任意の材質のもの、任意のファイ パー特性(ステップ形、グレーデッド形、その他) のもの、任意の大きのもの(例えば直径 25 μm ~ /mmのもの)が使用できる。内でも連続的による が変化している様な形状欠陥による光の散乱(も れ)損失の大きな光ファイバ、中心および周囲 加加が事差が小さく、散乱(もれ)損失の大きな光ファイバ等が好まれる。

又本発明で用いる半導体微粒子は、T102, MeSa STT103,CdS,GaP,In203,Heesa などの可視光で ホーエタレールからの水素発生に活性である半導 体微粒子の他、光による酸化還元反応に対して活 性な半導体微粒子である。

光マァイパーに半導体優粒子を担持させる方法 としては適常の固定方法が使用できるが、内でも 担持により反応系に限制される透過光の減少の少

100mg を作額した。この溶液ド/モル/gのNH4OH溶液を中和するまでゆっくりど浸拌しながら加え、さらド/wtsのH2PtCge・6H2O溶液を2mg,同じく/wtsのRuCg3・xH2O溶液を/mg 加えた。この溶液中ドコア径/30μm,外径200μm,長さ/0cmの関口角/s*の襞グレーデッドインデックス型 GeO2-SiO2 系光ファイベー(1)を多数浸漉させた。その後数ファイバー(1)を溶液より引きあげ、/00℃,30分乾燥後、300℃で/時間熱処理して半導体函数子つき光ファイバー(3)とした。

ここではファイバーの表面には 0.2~, μm の厚みの半導体 数粒子からなる コーティングが形成されていた。

こうして作成した半導体競粒子つき光ファイパー(3)を用いて、第1図に示す様な光酸化混元装置を以下の手脂で作成した。

まず、前記方法で作成した多数の半導体及粒子 つき光ファイバー(3)を、その/違を反応容器の選 (4) K 気密性を保ちながら固定してつり下げる。こ こで選(4) K は光憩化遊元反応Kより反応系より発 生したHzがスを排出するためのガス排出口(S)が設けられている。そして政光ファイベー(3)つき蓋(4)を、溶液住入口(6)および溶液排出口(7)つき反応容器(8) K 気密状態に取り付け、放反応容器上方に 500 m 高圧水銀灯(9)および集光用の凸レンズ (10)を設けた。

ここで遊(4) に対する半導体機粒子つき光ファイバー(3)の取り付け位置、高圧水銀灯(9)の位置および集光用凸レンズ(10)位置は、水銀灯(9)より服計した光が半導体機粒子つき光ファイバー(3) に鉄ファイバーの難口角 (//5⁹)よりもわずかに大きな入針角で入針する機位置関係を製整されている。

数光酸化温元装置を用い、反応容器(8)内 K3 0℃の CH3 OH 過度 25 モル系の CH3 OH-H2 O 混合液 (11) 25 0 m8 を満たすと共に同混合液を 25 m8 / 時の過度で溶液注入口(6) から注入し関排出液を溶液排出口(7) から排出した。 高圧水銀灯(9) を点径することにより溶液からH2 ガスが発生しガス排出口(5)より的 2000 m8/ 時の H2 ガス (0℃ / atm)が補集された。

(比較例)

実施例と同様に作成した TiO2-Pt-RuO2系のヒドロソル混合溶液に、平均孔径 20~30 μmのガラスフィルターを浸して細孔中に混合溶液を含ませ、実施例と同様に乾燥、熱処理して、半導体微粒子つきガラス多孔質体(12)を作成した。

こうして作成した半導体微粒子つきガラス多孔 質体(12)を無よ器に示す様な光酸化違元装置へ 光域した。第よ器において反応容器(13)は薄液 道知用タンク(14),温度計(15),気体補集用 管(16),反応液だめ部(17)からなる。反応液 だめ部(17)の底面積は約30 ㎡であり、反応液 だめ部の下方には下方より光を限針するためのHg ランプ(9)およびレンズ(10)が設けられている。

反応激だめ部ド実施例!と同様 30° C、、25 モル系 適度の $CH_3OH_{-}H_2O$ 混合液を 250 回髪 適しした後、 反応液だめ部(17)の下方より 500 可の水銀灯(9) の光を脱射した所約 245 回髪/時の H_2 ガス(0° C、 / atm)が補集された。

ここで反応後だめ部に充填された半導体機粒子

ここでファイバー表面に担持された半導体機能子の重量を装置に使用されたファイバー本数および半導体機能子つきファイバー(3)作成時の客液の減量から推定し、H2 ガスの免成効率を求めると的#000m2/hour-gTiO2(0℃,/atm换算)となった。

本実施例によれば、水銀灯より発生した光が直 (4)に固定された半導体機粒子つき光ファイベー(3) ドファイベーの関口角よりもわずかに大きなファイ 角で入射し、光ファイベー内を進行した後ファイベー 製造し、光ファイベー内を進行した。そこれが 実施例によれば光が半導体ではから、又本を での間に溶液の吸収・数乱の心配がない。又本で 液には光ファイベーとして GeO2-SiO2系の光ファイベーを 用いているためファイベーを面の イベーを用いているためファイベーを が良好であり光酸に還元用溶液に対して非常に安 定である。

次に本発明の効果を明らかにするために、従来 法を比較例として以下に説明する。

つきガラス多孔質体の重量および作成時の条件よりガラス多孔質体に担持された半導体微粒子の重量を推定し、H2ガスの発生効率を求めると約490m8/hour・gTiO2(O°C)/atm 換算)となった。

又上記半導体器粒子つきガラス多孔質体(12) のかわりにTiO2 微粒子 0.3 gを用い同装置で間様 に光照射を行なった所H2ガス発成効率は 3 0 mg/ hour·g TiO2 (G℃, / atm 検算) となった。

上紀比較例から明らかな遊り、本実施例では従来法と 較べて高率な酸化還元反応が行なわれていたことがわかる。

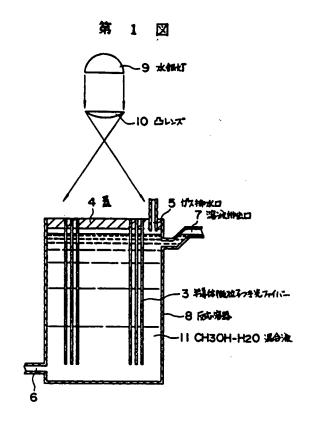
(発明の効果)

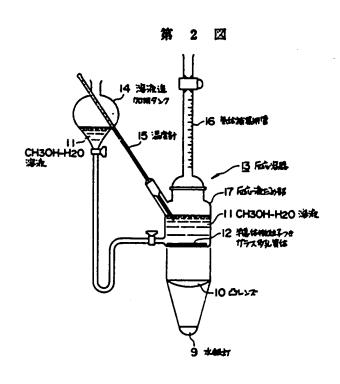
本発明によれば、実施例からもあきらかな辿り 従来法とくらべて効率の良いH2発生が行なえる光 酸化温元法である。特に本発明によれば、溶液内 ド光を透過させて光像化温元を行なわせていた従来後では効率が思かった溶液自体に吸光特性を持った溶液・数品を多くおこす溶液を用いても効率 食く光像化温元が行なえるものである。

4 図面の簡単な説明

第1日は本発明の光酸化選元法を実施するための光酸化選元法度の級略製明認であり、第2日は従来法の光酸化選元を実施するための光酸化選元 法立の概略裁明認である。

- (3) 半導体微粒子つき光ファイバー
- (9) 招きファー (10) レンズ
- (11) CH3OH-H2O 進合溶液
- (12) 半導体微粒子つき多孔質ガラス





Japanese Kokai Patent Application No. Sho 61[1986]-97102

JAPANESE PATENT OFFICE PATENT JOURNAL (A) KOKAI PATENT APPLICATION NO. SHO 61[1986]-97102

Int. Cl.⁴: C 01 B 3/06 B 01 J 19/12

Sequence Nos. for Office Use:

7918-4G 6812-4G

Filing No.: Sho 59[1984]-217569

Filing Date: October 17, 1984

Publication Date: May 15, 1986

No. of Inventions: 1 (Total of 4 pages)

Examination Request: Not filed

PHOTOREDOX METHOD

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[There are no amendments to this patent.]

Claims

1. A photoredox method whereby the redox reaction is brought about by bringing semiconductor microparticles and a solution into contact and irradiating the reaction system with light, said photoredox method being characterized in that the semiconductor microparticles are

carried on the side surfaces of optical fibers, thus producing optical fibers with attached semiconductor microparticles, and after bringing said optical fibers with attached semiconductor microparticles into contact with a solution, the reaction system at the side surfaces of the optical fibers is irradiated with light that passes through said optical fibers.

2. The photoredox method according to Claim 1, wherein said optical fiber is a step-index or graded-index optical fiber, and light is made to impinge on said optical fibers at an angle of incidence that is slightly greater than the [illegible] angle or aperture angle of said optical fiber.

Detailed explanation of the invention

Industrial application field

The present invention relates to a photoredox method that employs semiconductor microparticles and, in particular, relates to a photoredox method that has good efficiency.

Prior art

Research regarding microparticulate photocatalysts is experiencing rapid development. For example, there is a method whereby light energy is absorbed by semiconductor microparticles such as titanium oxide (TiO₂) or cadmium sulfide (CdS), and the electrons or holes generated thereby are used in order to reduce water molecules (or protons), thereby causing the oxidation of water or organic substances (e.g., Trigger, November 1983, pp. 47-53).

Examples of past photoirradiation methods carried out in order to accelerate the reactions in the aforementioned photoredox methods include (1) methods involving the introduction of semiconductor microparticles and a solution into a beaker, flask or other such container, and subsequent irradiation of the material with light wherein the semiconductor microparticles have sedimented at the bottom of the container, (2) methods involving stirring the aforementioned reaction liquid in order to suspend the semiconductor microparticles in the solution, followed by irradiation of the material with light with the particles in this state, and (3) methods involving supporting the semiconductor microparticles on a porous glass body, and subsequent irradiation of the material with light with this material immersed in a solution (for example, see [illegible] Industry Association 1983 Letters No. 375-376 (H32)).

Problems to be solved by the invention

Among the aforementioned photoredox methods, the methods presented in (1) are low-efficiency methods in which effective catalyst is restricted to the catalyst at the surface on which light impinges. With the methods presented in (2), the light can be scattered by the catalyst microparticles and lost from the system, or the solution itself can have characteristics whereby it absorbs or scatters light. In such case, there is the disadvantage that the efficiency is

poor, because irradiation with light cannot be effectively brought about. With the methods presented in (3), the catalyst that is irradiated with light is restricted to material near the surface of the porous body on which the light impinges, and as in (2), there is the disadvantage of poor efficiency when the solution itself has characteristics whereby it absorbs or scatters light.

The present invention has the objective of offering a photoredox method that has better efficiency than conventional photoredox methods and, in particular, has the objective of solving problems with conventional methods in regard to stimulating reactions in solutions that have characteristics that cause them to absorb or significantly scatter light.

Means to solve the problems

In order to solve the above problems, the present invention offers a photoredox method characterized in that semiconductor microparticles are supported on the side surfaces of optical fiber to produce optical fibers with attached semiconductor microparticles, and after bringing said optical fibers with attached microparticles into contact with a solution, light is made to irradiate the reaction system comprising the solution and the semiconductor microparticles via said optical fibers.

The optical fibers used in the present invention can be made from glass, plastic or any other material, and can have any fiber characteristics (step-form, graded or other) and any thickness (for example, materials of diameter 25 µm to 1 mm). Preferred among these materials are optical fibers that have large scattering loss (leakage) of light due to morphology defects and a thickness that varies continuously, and optical fibers that have a difference in index of refraction between the center and periphery, and which also have large scattering loss (leakage).

The semiconductor microparticles used in the preset invention are semiconductor microparticles that are active in terms of generating hydrogen from water-ethanol under the influence of visible light. Examples include TiO₂, SrTiO₃, CdS, GaP, In₂O₃ and MoS₂. Other such particles are semiconductor microparticles that are active in terms of redox reactions brought about by light.

The method for supporting the semiconductor microparticles on the optical fiber can be a common fixing method, but among such methods, those are preferred whereby supporting of the material causes little attenuation of transmissive light that is used to irradiate the reaction system.

In the present invention, light can be conducted into the reaction system via the optical fiber by making the light impinge upon the optical fiber. Examples of methods for bringing about impingement of light on the optical fiber that may be cited include (1) methods wherein light is made to impinge on the optical fiber at an angle that is close to the aperture angle of the optical fiber, and in particular, at an angle that is slightly larger than the aperture angle (effective when ordinary optical fiber is used for the optical fiber), and (2) methods wherein light is made to

impinge on the optical fiber at an appropriate angle (smaller than the aperture angle; effective when an optical fiber is used that has extremely high scattering loss).

By means of the present invention, the surface area of the reaction system that can participate in the reaction is readily increased by increasing the number of optical fibers having affixed semiconductor microparticles that are loaded into the reaction vessel.

The present invention is described in additional detail below.

Application example

First, special reagent-grade $TiCl_4$ was hydrolyzed to produce 100 mL of TiO_2 hydrosol solution with a concentration of 2.274 mol/L based on TiO_2 . 1 mol/L NH₄OH solution was then added slowly to this solution while stirring in order to effect neutralization, and 2 mL of 1 wt% $H_2PtCl_6\cdot 6H_2O$ solution and 1 mL of 1 wt% $RuCl_3\cdot xH_2O$ solution were added. Multiple strands of quasi-graded index GeO_2 -SiO₂ system optical fiber (1) having a core diameter of 150 µm, an external diameter of 200 µm, a length of 10 cm and an aperture angle of 15° were then immersed in this solution. Subsequently, said fiber (1) was removed from the solution, dried for 30 min at $100^\circ C$, and thermally treated for 1 h at $500^\circ C$ to produce optical fiber (3) with attached semiconductor particles.

By this means, a coating composed of semiconductor microparticles was formed on the surface of said fibers at a thickness of 0.2-1 μm .

Optical fibers (3) with attached semiconductor microparticles produced in this manner were used, and a photoredox device of the type shown in Figure 1 was produced by the following procedure.

First, multiple optical fibers (3) having attached semiconductor microparticles produced by the above method were fixed at one end in the lid (4) of the reaction vessel so that air-tightness was maintained, and the fibers were allowed to hang. A gas discharge opening (5) was provided in the lid (4) in order to exhaust H₂ gas generated by the reaction system in the photoredox reaction. Then, the lid (4) having said optical fibers (3) was attached in an air-tight condition to a reaction vessel (8) having a solution discharge opening (7) and a solution introduction opening (6), and a 500 W high-pressure mercury lamp (9) and convex condensing lens (10) were installed above said reaction vessel.

The attachment position with respect to the lid (4) of the optical fibers (3) having attached semiconductor microparticles, the location of the high-pressure mercury lamp (9) and the location of the condensing convex lens (10) were adjusted to produce positional relationships such that the light emanating from the mercury lamp (9) was incident on the optical fibers (3) with attached semiconductor microparticles at an angle of incidence that was slightly larger than the aperture angle of said fibers (15°).

Said photoredox device was used, and the reaction vessel (8) was filled with 250 mL of a 30°C CH₃OH-H₂O mixed liquid (11) having a CH₃OH concentration of 25 mol%. Simultaneously, the same mixed liquid was introduced from the solution introduction opening (6) at a rate of 25 mL/h, and discharge liquid was also similarly discharged from the solution discharge opening (7). When the high-pressure mercury lamp (9) was turned on, H₂ gas was generated from the solution, and H₂ gas was collected at about 2000 mL/h (0°C, 1 atm) from the gas exhaust opening (5).

The weight of the semiconductor microparticles supported on the fiber surface was hypothesized from the decrease in the amount of solution during production of the fibers (3) with attached semiconductor microparticles and the number of fibers used in producing the device. The H₂ gas generation efficiency was then calculated to be about 4000 mL/h·g TiO₂ (0°C, 1 atm).

In this application example, the light generated by the mercury lamp was made to impinge upon the optical fibers (3) with attached semiconductor microparticles and fixed in the lid (4) and the angle of incidence was slightly larger than the aperture angle of the fiber. After traveling through the optical fiber, the light then impinged upon the semiconductor microparticles on the sides of the fibers. Thus, by means of this application example, the light did not pass through the solution in order to irradiate the semiconductor microparticles. In other words, there is no concern over absorption or scattering of light by the solution. Moreover, in this application example, the durability of the fiber surfaces is good because GeO₂-SiO₂ system optical fiber was used for the fiber, and the fibers are thus extremely stable with respect to the photoredox solution.

A conventional method is presented below using a comparative example in order to clarify the effects of the present invention.

Comparative example

A glass filter with an average pore diameter of 20-30 µm was immersed in a TiO₂-Pt-RuO₂ hydrosol mixed solution produced in the same manner as in the application example, so that the pores were infused with the mixed solution. The material was then dried and thermally treated in the same manner as in the application example, thus producing a glass porous material (12) with attached semiconductor microparticles.

The glass porous material (12) with attached semiconductor microparticles produced in this manner was then packed into the type of photoredox device shown in Figure 2. In Figure 2, the reaction vessel (13) comprises a solution replenishment tank (14), a temperature gauge (15), a gas collection line (16), and a reaction liquid reservoir (17). The bottom surface area of the reaction liquid reservoir (17) is about 30 cm². A Hg lamp (9) and lens (10) are provided to cause light to impinge from below on the bottom of the reaction liquid reservoir.

As in Application Example 1, the device was filled with 250 mL of a 30°C CH₃OH-H₂O mixed liquid having a [methanol] concentration of 25 mol%, and the bottom of the reaction liquid reservoir (17) was irradiated from below with light from a 500 W mercury lamp (9). As a result, 245 mL/h of H₂ gas was collected (0°C, 1 atm).

The weight of the semiconductor microparticles supported on the glass porous material was estimated based on parameters at the time of production of the device and the weight of the glass porous material with attached semiconductor microparticles packed into the reaction liquid reservoir. The H₂ gas generation efficiency was calculated to be about 490 mL/h·g TiO₂ (0°C, 1 atm).

The H₂ gas production efficiency was 50 mL/h·g TiO₂ (0°C, 1 atm) when 0.5 g of TiO₂ microparticles was used instead of the aforementioned glass porous material (12) with attached semiconductor microparticles and irradiation was carried out in the same manner using the same device.

A stirring device was attached to the reaction liquid reservoir (17) of the aforementioned device, and when irradiation was carried out using the above 0.5 g of TiO_2 microparticles while stirring, the H_2 gas generation efficiency was $16 \text{ mL/h} \cdot \text{g}$ TiO_2 (0°C, 1 atm).

As is clear from the above comparative example, the high-efficiency redox reaction occurring in the application example was higher in efficiency than that of the conventional methods.

Effect of the invention

It is clear from the application example that the present invention provides a photoredox method whereby H_2 is generated with better efficiency relative to conventional methods. In particular, by means of the present invention, photoredox is carried out with good efficiency, even when using a solution that causes significant scattering or a solution that has light-absorbing characteristics, which has caused poor efficiency in conventional methods in which photoredox has been carried out by passing light through the solution.

Brief description of the figures

Figure 1 is a schematic explanatory diagram of the photoredox device used for carrying out the photoredox method of the present invention. Figure 2 is a schematic explanatory diagram of a photoredox device used in order to carry out photoredox in a conventional method.

- 3 Optical fiber with attached semiconductor microparticles.
- 9 Mercury high-pressure lamp
- 10 Lens
- 11 CH₃OH-H₂O mixed solution
- 12 Porous glass with attached semiconductor microparticles

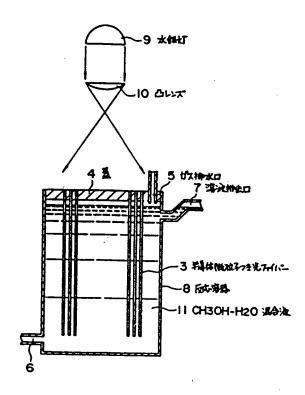


Figure 1

- Key: 3 Fiber with attached semiconductor microparticles
 - 4 Lid
 - 5 Gas exhaust opening
 - 7 Mixed liquid discharge opening
 - 8 Reaction vessel
 - 9 Mercury lamp
 - 10 Convex lens
 - 11 CH₃OH-H₂O mixed liquid

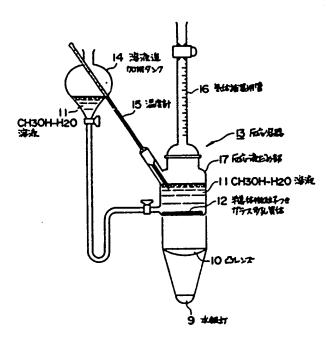


Figure 2

Key:	9	Mercury lamp
	10	Convex lens
	11	CH ₃ OH-H ₂ O solution
	12	Glass porous material with attached semiconductor microparticles
	13	Reaction vessel
	14	Solution replenishment tank
	15	Temperature gauge
	16	Gas collection line
	17	Reaction solution reservoir

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